

### SH163 High Sensitivity Hall Effect Latch

SH163 is a High Sensitivity Hall-effect Latch designed in advanced DMOS technology. The following are integrated on a single silicon chip: voltage regulator, reverse bias protection, ESD protection, Hall voltage generator, chopper stabilized small-signal amplifier, Schmitt trigger, open-drain output and thermal shut-down protection. Superior high-temperature performance is made possible through a dynamic offset cancellation that utilizes chopper-stabilization.

#### Features

- Dynamic offset cancellation
- High sensitivity (3mT typ.)
- Open-drain output
- Maximum output sink current 100mA
- Thermal shut-down protection
- Stable temperature characteristics
- Good ESD protection. (HBM4kV min.)
- Reverse bias protection

#### Typical Applications

- High temperature Fan motor
- 3 phase BLDC motor
- Speed sensing
- Position sensing
- Current sensing
- Revolution counting

#### Order Information

Order No.	Part No.	Temperature	Package	Packing
SH163KSO-TR	SH163	K	SO	TR

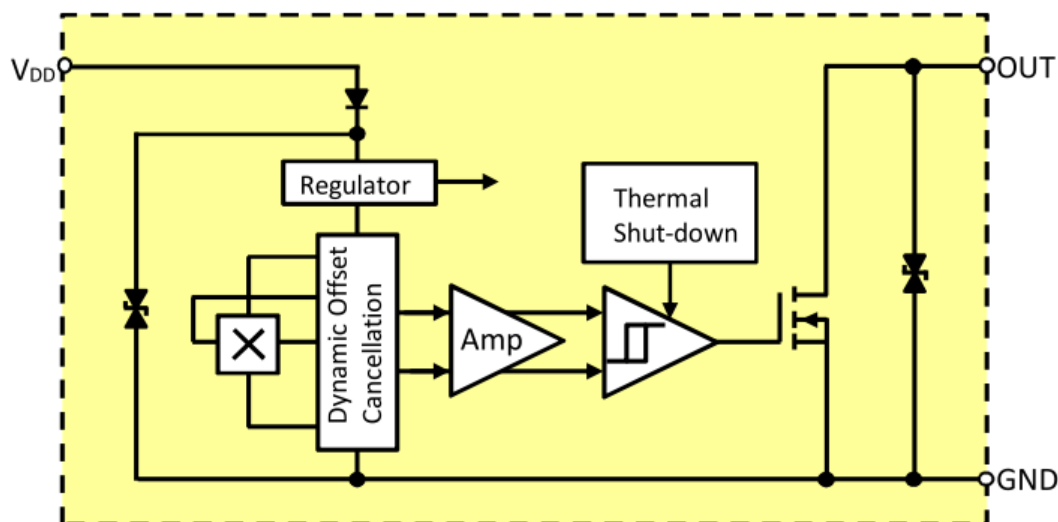
Legend:

Temperature Code: K (-40°C~125°C)

Package Code: SO (SOT23)

Packing Code: TR (Tape & Reel, 3,000pcs/Reel)

#### Functional Block Diagram



**Absolute Maximum Ratings** ( $T_A=25^\circ\text{C}$ )

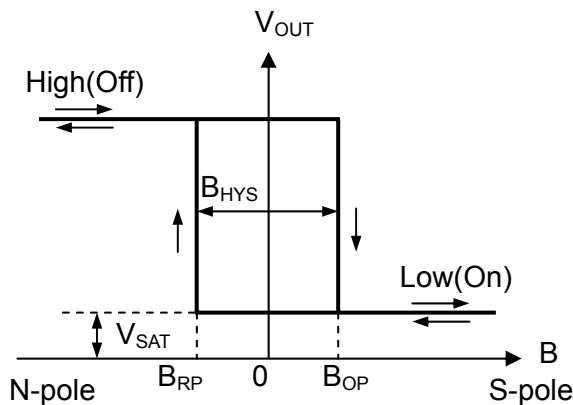
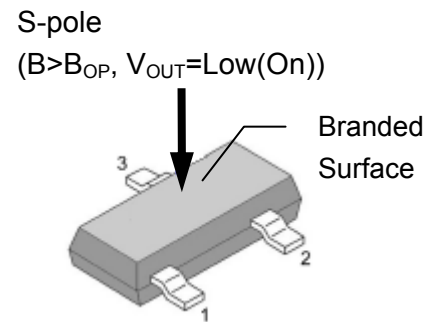
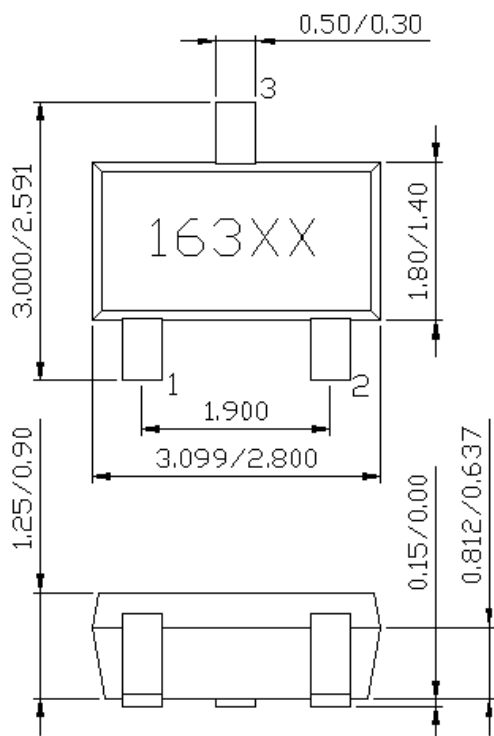
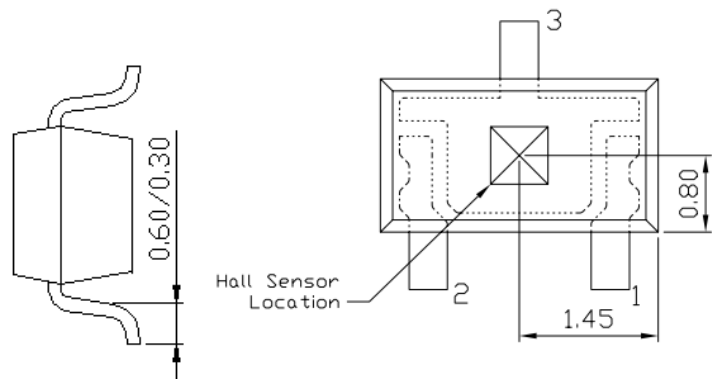
Parameter	Symbol	Value		Unit
		Min	Max	
Supply Voltage	$V_{DD}$	-28	28	V
Output Voltage	$V_{OUT}$	-0.3	28	V
Output Current	$I_{SINK}$	-	100	mA
Operating Temperature Range(K)	$T_A$	-40	125	$^\circ\text{C}$
Storage Temperature Range	$T_S$	-65	150	$^\circ\text{C}$
Maximum Junction Temperature	$T_J$	-	150	$^\circ\text{C}$
Power Dissipation	$P_D$	-	230	mW

**Electrical Characteristics** ( $T_A=25^\circ\text{C}$ ,  $V_{DD}=12\text{V}$ )

Parameter	Test Condition	Symbol	Value			Unit
			Min	Typ	Max	
Supply Voltage		$V_{DD}$	3.5	-	24	V
Consumption Current	$V_{OUT}=\text{High}$	$I_{DD}$	-	3.5	8	mA
Output Saturation Voltage	$I_{SINK}=80\text{mA}$ , $V_{OUT}=\text{Low}$	$V_{SAT}$	-	-	0.2	V
Output Leakage Current	$V_{OUT}=\text{High}$	$I_{LEAK}$	-	-	10	$\mu\text{A}$
Output Rise time	$R_L=1\text{k}\Omega$ , $C_L=20\text{pF}$	$t_R$	-	-	0.5	$\mu\text{s}$
Output Fall time	$R_L=1\text{k}\Omega$ , $C_L=20\text{pF}$	$t_F$	-	-	0.5	$\mu\text{s}$
Thermal Shut-down Temperature		$T_{SD}$	150	-	-	$^\circ\text{C}$
Thermal Shut-down Hysteresis		$T_{SDH}$	-	30	-	$^\circ\text{C}$
Electro-Static Discharge	HBM		4	-	-	kV

**Magnetic Characteristics** ( $T_A=25^\circ\text{C}$ ,  $V_{DD}=12\text{V}$ )

Parameter	Test Condition	Symbol	Value			Unit
			Min	Typ	Max	
Operate Point	S pole to branded side	$B_{OP}$	0	-	6	mT
Release Point	N pole to branded side	$B_{RP}$	-6	-	0	mT
Hysteresis		$B_{HYS}$	-	6	-	mT


**Switching Characteristics**

**SO-package**
**Package Dimension, Sensor Location and Marking**
**SO-package: SOT23**
**(Upper View)**

**Hall sensor location**
**(Bottom View)**

**NOTES:**

- PINOUT:  
Pin 1  $V_{DD}$   
Pin 2 Output  
Pin 3 GND
- Controlling dimension: mm;
- Lead thickness after solder plating will be 0.254mm maximum.